

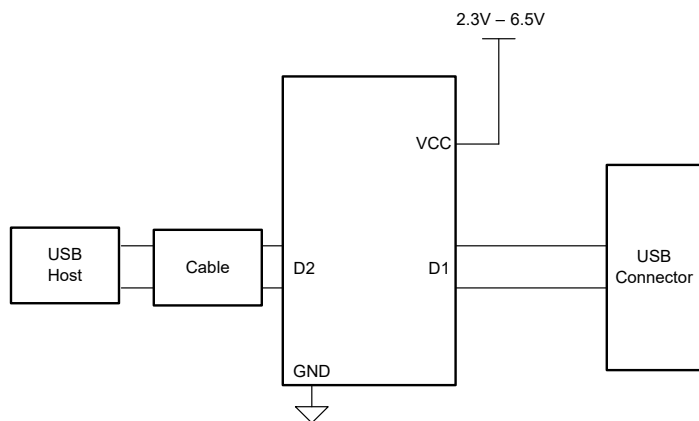
TUSB211A-Q1 車載向け、USB 2.0 480Mbps 高速シグナルコンディショナ

1 特長

- 車載アプリケーション向けに AEC-Q100 認定済み
 - デバイス温度グレード 2: -40°C ~ 105°C
- 広い電源電圧範囲: 2.3 ~ 6.5V
- USB 切断時およびシャットダウン時の非常に低い消費電力
- USB 2.0 High-Speed 信号のコンディショニングを提供
- USB 2.0、OTG 2.0、BC 1.2 に対応
- Low-Speed、Full-Speed、High-Speed 信号処理のサポート
- 特定のホストやデバイスに非依存
- 最大 5m のケーブル長をサポート
 - 外付けのプルダウン抵抗により 4 つの信号 EQ (エッジブーストと DC ブースト) 設定を選択可能
- 2 つの TUSB211A-Q1 デバイスを使って最大 10m のケーブル長に対応
- スケーラブルなソリューション - 損失が大きいアプリケーションに対応するため、デバイスをディジーチェーン接続可能
- TUSB211、212、214、216、217A (3.3V) とピン互換

2 アプリケーション

- 車載用インフォテインメントおよびクラスタ
- 車載ヘッドユニット
- アクティブケーブル、延長ケーブル、バックプレーン



概略回路図

3 概要

TUSB211A-Q1 は第 3 世代 USB™ 2.0 High Speed シグナルコンディショナで、伝送チャネルでの AC 損失 (容量性負荷による) および DC 損失 (抵抗損失による) を補償するように設計されています。

TUSB211A-Q1 には、エッジブースタにより USB 2.0 High Speed 信号の遷移エッジを高速化し、DC ブースト機能により静的電圧レベルを上げる特許取得済みの設計が採用されています。

また、TUSB211A-Q1 はプリイコライゼーション機能を備えているため、長いケーブルを使用するアプリケーションで ISI (符号間干渉) ジッタを補償できます。USB Low Speed および Full Speed 信号特性は、TUSB211A-Q1 による影響を受けません。

TUSB211A-Q1 は、パケットタイミングの変更も伝搬遅延またはレイテンシの追加もせずに信号品質を向上させることができます。

TUSB211A-Q1 により、最長 5 メートルのケーブルを使用したシステムで、USB 2.0 High Speed 近端アイコンプライアンスに合格することが可能になります。

TUSB211A-Q1 は、USB On-The-Go (OTG) および Battery Charging (BC) プロトコルにも対応しています。

デバイスの比較

部品番号	パッケージ ⁽¹⁾	動作温度 (T _A) °C
TUSB211A	RWB (X2QFN, 12)	0 ~ 70
TUSB211AI		-40 ~ 85
TUSB211A-Q1		-40 ~ 105

パッケージ情報

部品番号	パッケージ ⁽¹⁾	パッケージサイズ ⁽²⁾
TUSB211A-Q1	RWB (X2QFN, 12)	1.6mm × 1.6mm

- (1) 詳細については、[セクション 10](#) を参照してください。
 (2) パッケージサイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。



Table of Contents

1 特長	1	6.3 Feature Description.....	7
2 アプリケーション	1	6.4 Device Functional Modes.....	7
3 概要	1	7 Application and Implementation	9
4 Pin Configuration and Functions	2	7.1 Application Information.....	9
5 Specifications	4	7.2 Typical Application.....	9
5.1 Absolute Maximum Ratings.....	4	7.3 Power Supply Recommendations.....	14
5.2 ESD Ratings.....	4	7.4 Layout.....	14
5.3 Recommended Operating Conditions.....	4	8 Device and Documentation Support	16
5.4 Thermal Information.....	4	8.1 ドキュメントの更新通知を受け取る方法.....	16
5.5 Electrical Characteristics.....	5	8.2 サポート・リソース.....	16
5.6 Switching Characteristics.....	5	8.3 Trademarks.....	16
5.7 Timing Requirements.....	6	8.4 静電気放電に関する注意事項.....	16
5.8 Typical Characteristics.....	6	8.5 用語集.....	16
6 Detailed Description	7	9 Revision History	16
6.1 Overview.....	7	10 Mechanical, Packaging, and Orderable Information	16
6.2 Functional Block Diagram.....	7		

4 Pin Configuration and Functions

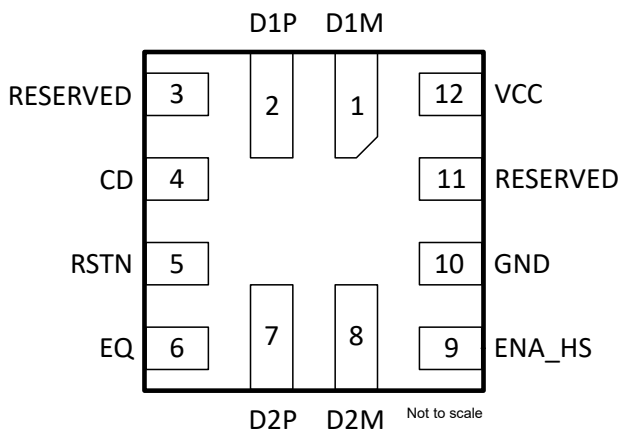


図 4-1. TUSB211A-Q1 RWB 12-Pin X2QFN (Top View)

表 4-1. Pin Functions

PIN		TYPE ⁽¹⁾	INTERNAL PULLUP/PULLDOWN	DESCRIPTION
NAME	NO.			
EQ	6	I	N/A	USB High-speed EQ select via external pull down resistor. Both edge boost and DC boost are controlled by a single pin. Sampled upon power up. Does not recognize real time adjustments. Auto selects EQ LEVEL = 3 when left floating.
RESERVED	11	I	500kΩ PU	Reserved pin for TI test purposes. Leave floating or connect external capacitor to GND for normal operation.
ENA_HS	9	I/O	N/A	After reset: Output signal ENA_HS. Flag indicating that channel is in High-speed mode. Asserted upon: 1. Detection of USB-IF High-speed test fixture from an unconnected state followed by transmission of USB TEST_PACKET pattern. 2. Squelch detection following USB reset with a successful HS handshake [HS handshake is declared to be successful after single chirp J chirp K pair where each chirp is within 18μs – 128μs].
D2P	7	I/O	N/A	USB High-speed positive port.
D2M	8	I/O	N/A	USB High-speed negative port.
GND	10	P	N/A	Ground
D1M	1	I/O	N/A	USB High-speed negative port.
D1P	2	I/O	N/A	USB High-speed positive port.
RESERVED	3	I/O	500kΩ PU 1.8 MΩ PD	Reserved pin for TI test purposes. Leave floating for normal operation.
VCC	12	P	N/A	Supply power
RSTN	5	I	500kΩ PU 1.8 MΩ PD	Device disable/enable. Low – Device is at reset and in shutdown, and High - Normal operation. Recommend 0.1μF external capacitor to GND to allow for clean power on reset if not driven. If the pin is driven, it must be held low until the supply voltage for the device reaches within specifications.
CD	4	O	When RSTN asserted there is a 500kΩ PD	After reset: Output CD. Flag indicating that a USB device is attached (connection detected). Asserted from an unconnected state upon detection of DP or DM pull-up resistor. De-asserted upon detection of disconnect.

(1) I = input, O = output, P = power

5 Specifications

5.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Supply voltage range	VCC	−0.3	7	V
Voltage range USB data	DxP, DxM	−0.3	5.5	V
Voltage range on EQ pin	EQ	−0.3	1.98	V
Voltage range other pins	RSTN	−0.3	5.5	V
Storage temperature, T _{stg}		−65	150	°C
Maximum junction temperature, T _{J(max)}			125	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

5.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000
		Charged-device model (CDM), per AEC Q100-011 ⁽²⁾	±750

- (1) AEC Q100-002 HBM ESD Classification Level 2
 (2) AEC Q100-011 CDM ESD Classification Level C4A

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	2.3	5	6.5	V
T _A	Operating free-air temperature (AEC-Q100)	−40		105	°C
T _J	Junction temperature (AEC-Q100)			115	°C
DxP, DxM	Voltage range USB data	0		3.6	V
EQ	Voltage range EQ pin	0		1.98	V
DIGITAL	Voltage range other pins (RSTN)	0		3.6	V

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		RWB (X2QFN)	UNIT
		12 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	137.4	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	62	°C/W
R _{θJB}	Junction-to-board thermal resistance	67.2	°C/W
ψ _{JT}	Junction-to-top characterization parameter	1.9	°C/W
ψ _{JB}	Junction-to-board characterization parameter	67.3	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

5.5 Electrical Characteristics

Over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
POWER						
I _{ACTIVE_HS}	High Speed Active Current	USB channel = HS mode. 480Mbps traffic. V _{CC} supply stable, with EQ = Max		22	36	mA
I _{IDLE_HS}	High Speed Idle Current	USB channel = HS mode, no traffic. V _{CC} supply stable, EQ = Max		22	36	mA
I _{HS_SUSPEND}	High Speed Suspend Current	USB channel = HS Suspend mode. V _{CC} supply stable		0.75	1.4	mA
I _{FS}	Full-Speed Current	USB channel = FS mode, 12Mbps traffic, V _{CC} supply stable		0.75	1.4	mA
I _{DISCONN}	Disconnect Power	Host side application. No device attachment.		0.80	1.4	mA
I _{SHUTDN}	Shutdown Power	RSTN driven low, V _{CC} supply stable		60	115	μA
CONTROL PIN LEAKAGE						
I _{LKG_FS}	Pin failsafe leakage current for RSTN	V _{CC} = 0V, pin at V _{IH, max}		10	15	μA
INPUT RSTN						
V _{IH}	High level input voltage		1.5		3.6	V
V _{IL}	Low-level input voltage		0		0.5	V
I _{IH}	High level input current	V _{IH} = 3.6V, R _{PU} enabled			±15	μA
I _{IL}	Low level input current	V _{IL} = 0V, R _{PU} enabled			±20	μA
INPUT EQ						
R _{EQ_LVL0}	External pulldown resistor for EQ Level 0				160	Ω
R _{EQ_LVL1}	External pulldown resistor for EQ Level 1		1.5	1.8	2	kΩ
R _{EQ_LVL2}	External pulldown resistor for EQ Level 2		3.4	3.6	3.96	kΩ
R _{EQ_LVL3}	External pulldown resistor for EQ Level 3 to remove upper limit for resistor value, can be left open		7.5			kΩ
OUTPUTS CD, ENA_HS						
V _{OH}	High level output voltage for CD and ENA_HS	I _O = -50μA, V _{CC} >= 3.0V	2.5			V
V _{OH}	High level output voltage for CD	I _O = -25μA, V _{CC} = 2.3V	1.7			V
V _{OH}	High level output voltage for ENA_HS	I _O = -25μA, V _{CC} = 2.3V	1.8			V
V _{OL}	Low level output voltage for CD and ENA_HS	I _O = 50μA			0.3	V
DxP, DxM						
C _{IO_DXX}	Capacitance to GND	Measured with VNA at 240MHz, V _{CC} supply stable, Redriver off		2.5		pF

(1) All typical values are at V_{CC} = 5V, and T_A = 25°C.

5.6 Switching Characteristics

Over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
DxP, DxM USB Signals						
F _{BR_DXX}	Bit Rate	USB channel = HS mode. 480Mbps traffic. V _{CC} supply stable			480	Mbps
t _{R/F_DXX}	Rise/Fall time		100			ps

(1) All typical values are at V_{CC} = 5V, and T_A = 25°C.

5.7 Timing Requirements

		MIN	NOM	MAX	UNIT
POWER UP TIMING					
T_{RSTN_PW}	Minimum width to detect a valid RSTN signal assert when the pin is actively driven low	100			μs
T_{STABLE}	VCC must be stable before RSTN de-assertion	300			μs
T_{READY}	Maximum time needed for the device to be ready after RSTN is de-asserted.			500	μs
T_{RAMP}	V_{CC} ramp time			100	ms
T_{RAMP}	V_{CC} ramp time	0.2			ms

5.8 Typical Characteristics

The typical characteristics shown in this section apply to near-end eye measurements taken at nominal conditions. The eyes are measured with various pre-channel cable lengths applied at the input or post-channel cable lengths applied at the output of the TUSB211A-Q1 as indicated.

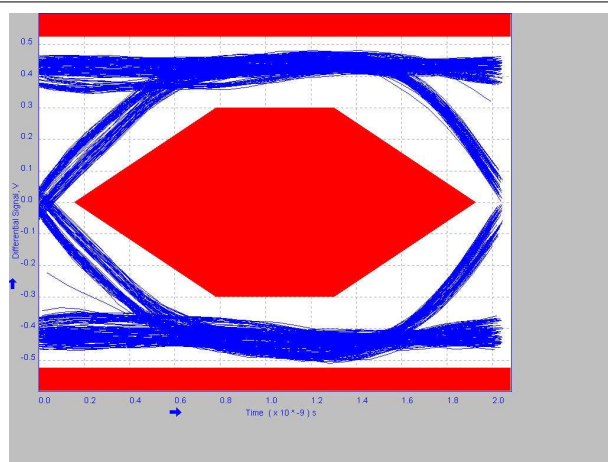


図 5-1. 2 Meter Pre-Channel With TUSB211A-Q1 EQ=1

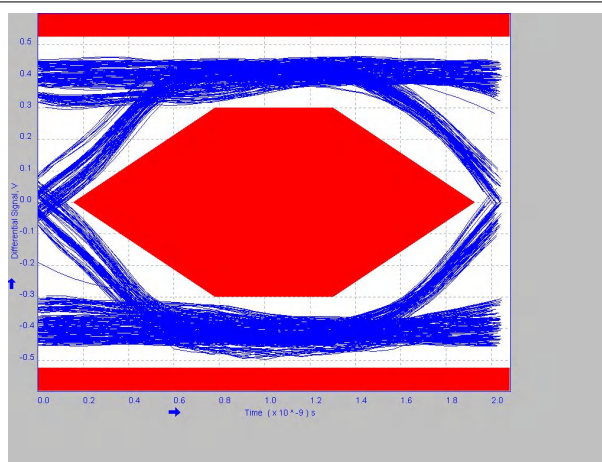


図 5-2. 5 Meter Pre-Channel With TUSB211A-Q1 EQ=2

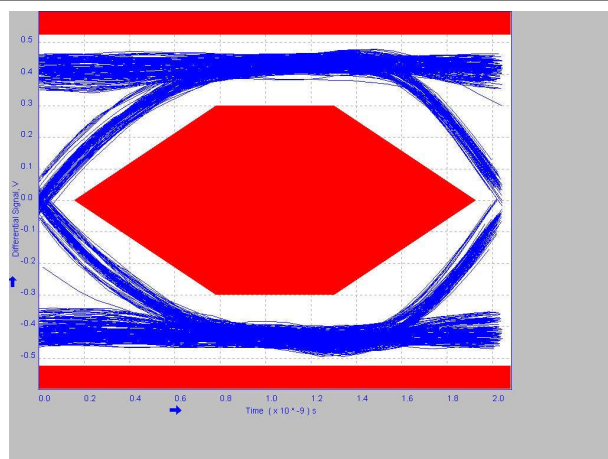


図 5-3. 2 Meter Post-Channel With TUSB211A-Q1 EQ=1

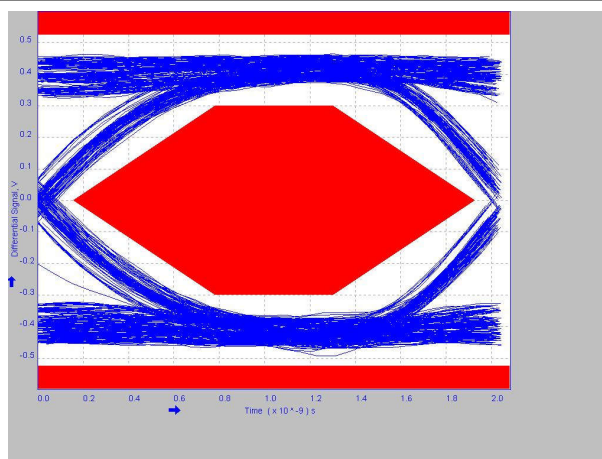


図 5-4. 4 Meter Post-Channel With TUSB211A-Q1 EQ=2

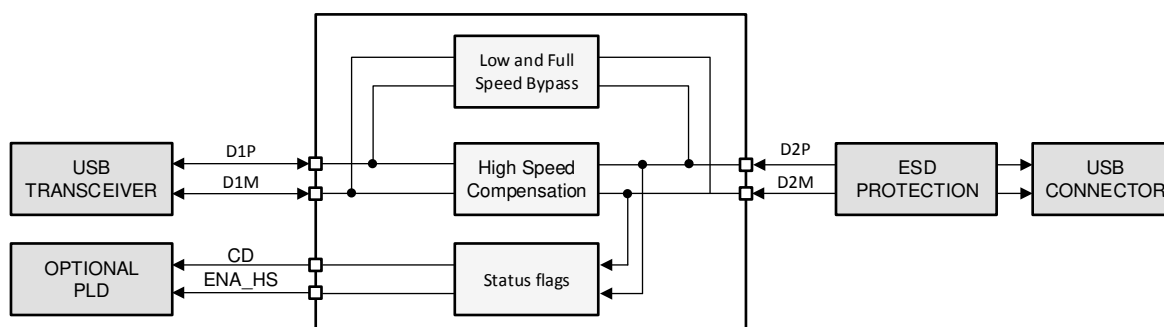
6 Detailed Description

6.1 Overview

The TUSB211A-Q1 is a USB High-Speed (HS) signal conditioner designed to compensate for ISI signal loss in a transmission channel. TUSB211A-Q1 has a patented design for USB Low Speed (LS) and Full Speed (FS) signals. It does not alter the signal characteristics. HS signals are compensated. The design is compatible with USB On-The-Go (OTG) and Battery Charging (BC) specifications.

Programmable signal gain through an external resistor permits fine tuning device performance to optimize signals. This helps pass USB HS electrical compliance tests at the connector. The TUSB211A-Q1 allows application in series to cover longer distances, or high loss transmission paths. A maximum of 4 devices can be daisy-chained.

6.2 Functional Block Diagram



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6.3 Feature Description

6.3.1 High-Speed EQ

The high-speed EQ (combination of edge boost and DC boost) improves the eye width for USB2.0 high-speed signals. It is direction independent, which makes it compatible to OTG systems. The EQ pin is configuring the EQ strength with different values of pull down resistors to set 4 levels of EQ.

6.4 Device Functional Modes

6.4.1 Low-Speed (LS) Mode

TUSB211A-Q1 automatically detects an LS connection and does not enable signal compensation. CD pin is asserted high but ENA_HS will be low.

6.4.2 Full-Speed (FS) Mode

TUSB211A-Q1 automatically detects an FS connection and does not enable signal compensation. CD pin is asserted high but ENA_HS will be low.

6.4.3 High-Speed (HS) Mode

TUSB211A-Q1 automatically detects an HS connection and will enable signal compensation as determined by the external pull down resistance on its EQ pin.

CD pin and ENA_HS pin are asserted high when high-speed EQ is active.

6.4.4 High-Speed Downstream Port Electrical Compliance Test Mode

TUSB211A-Q1 will detect an HS compliance test fixture and enter the downstream port high-speed eye diagram test mode. CD pin will be low and ENA_HS pin is asserted high when TUSB211A-Q1 is in HS eye compliance test mode.

If the RSTN pin is asserted low and de-asserted high while TUSB211A-Q1 is operating in HS functional mode, then TUSB211A-Q1 will transition to HS eye compliance test mode, the CD asserts low, and ENA_HS remains high. When all this occurs, signal compensation is enabled.

6.4.5 Shutdown Mode

TUSB211A-Q1 can be disabled when its RSTN pin is asserted low. DP, DM traces are continuous through the device in shutdown mode. The USB channel is still fully operational, but there is neither signal compensation, nor any indication from the CD pin as to the status of the channel.

表 6-1. CD and ENA_HS Pins in Different Modes

MODE	CD	ENA_HS
Low-speed	HIGH	LOW
Full-speed	HIGH	LOW
High-speed	HIGH	HIGH
High-speed downstream port electrical test	LOW	HIGH
Shutdown	LOW	LOW

7 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

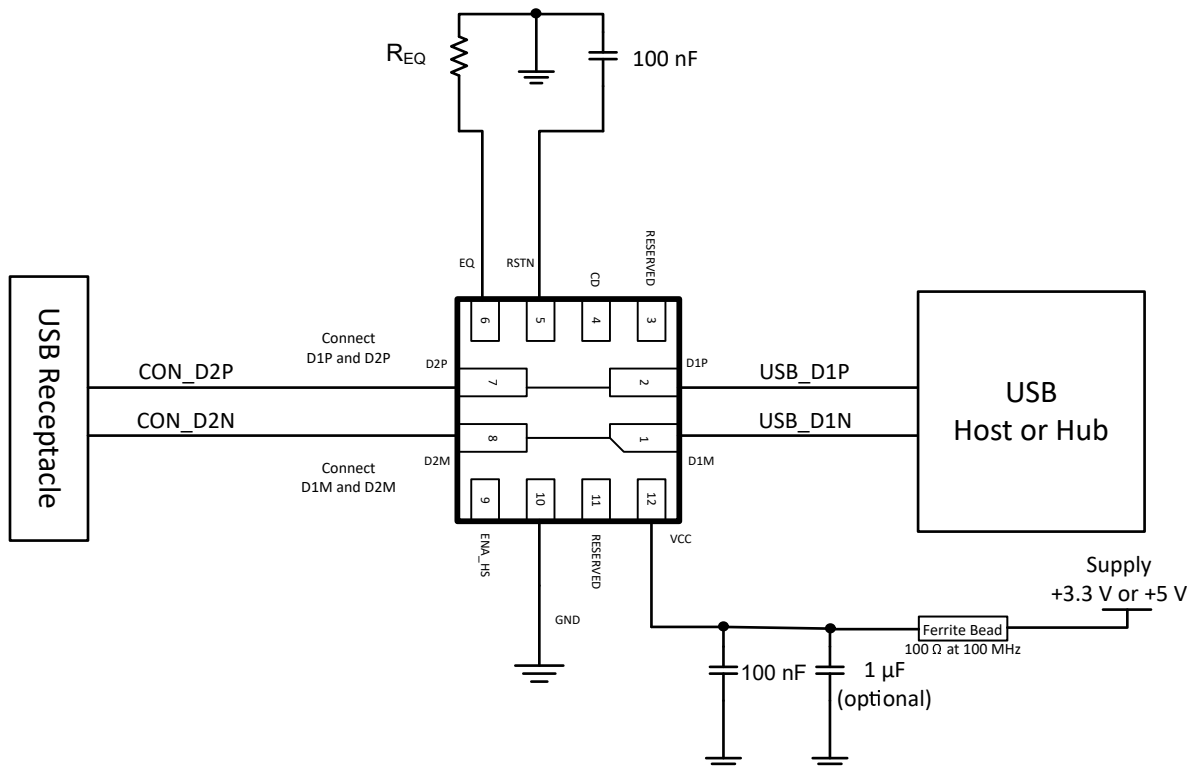
7.1 Application Information

The purpose of the TUSB211A-Q1 is to restore the signal integrity of a USB High-speed channel up to the USB connector. The loss in signal quality stems from reduced channel bandwidth due to high loss PCB trace and other components that contribute a capacitive load. This can cause the channel to fail the USB near end eye mask. Proper use of the TUSB211A-Q1 can help to pass this eye mask.

A secondary purpose is to use the CD pin of the TUSB211A-Q1 to control other blocks on the customer platform, if so desired.

7.2 Typical Application

A typical application for TUSB211A-Q1 is shown in 図 7-1. In this setup, D2P and D2M face the USB connector while D1P and D1M face the USB host. The orientation may be reversed [that is, D2 faces transceiver and D1 faces connector].



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図 7-1. TUSB211A-Q1 Reference Schematic

7.2.1 Design Requirements

TUSB211A-Q1 requires a valid reset signal as described in the *Power Supply Recommendations* section. The capacitor at RSTN pin is not required if a micro controller drives the RSTN pin according to recommendations.

For this design example, use the parameters provided in 表 7-1.

表 7-1. Design Parameters for 3.3V Supply With Low to Medium Loss System

PARAMETER			VALUE ⁽¹⁾
V _{CC}			3.3V ±10%
I ² C support required in system (Yes/No)			No
Edge and DC Boost	R _{EQ}	EQ Level	EQ Level 0: R _{EQ} = 0Ω
	0Ω	0	
	1.8kΩ ±1%	1	
	3.6kΩ ±1%	2	
	Do Not Install (DNI)	3	

- (1) These parameters are starting values for a low to medium loss system. Further tuning might be required based on specific host or device as well as cable length and loss profile. These settings are not specific to a 3.3V supply system and could be applicable to 5V supply system as well.

7.2.2 Detailed Design Procedure

The best EQ setting is dependent upon the signal chain loss characteristics of the target platform. The recommendation is to start with EQ Level 0, and then increment to EQ Level 1, and so on.

For the TUSB211A-Q1 to recognize any change to the EQ setting, the RSTN pin must be toggled. This is because the EQ pin is latched on power up and the pin is ignored thereafter.

Placement of the device is also dependent on the application goal. 表 7-2 provides TI recommendations.

表 7-2. Platform Placement Guideline

PLATFORM GOAL	SUGGESTED TUSB211A-Q1 PLACEMENT
Pass USB Near End Mask at the receptacle	Close to measurement point (connector)
Pass USB Far End Eye Mask at the plug	Close to USB PHY
Cascade multiple TUSB211A-Q1s to improve device enumeration	Midway between each USB interconnect

表 7-3. Table of Recommended Settings

EQ settings ⁽¹⁾ for channel loss	
Pre-channel cable length (Between USB PHY and TUSB211A-Q1)	EQ
0-3 meter	Level 0
2-5 meter	Level 1
Post-channel cable length (Between TUSB211A-Q1 and inter-connect)	EQ
0-2 meter	Level 0
1-4 meter	Level 1

- (1) These parameters are starting values for different cable lengths. Further tuning might be required based on specific host or device as well as cable length and loss profile.

7.2.2.1 Test Procedure to Construct USB High-Speed Eye Diagram

注

USB-IF certification tests for High-speed eye masks require the *mandated use* of the USB-IF developed test fixtures. These test fixtures do not require the use of oscilloscope probes. Instead they use SMA cables. More information can be found at the USB-IF Compliance Updates Page. It is located under the *Electrical Specifications* section, ID 86 dated March 2013.

The following procedure must be followed before using any oscilloscope compliance software to construct a USB High-speed Eye Mask:

7.2.2.1.1 For a Host Side Application

1. Configure the TUSB211A-Q1 to the desired EQ setting.
2. Power on (or toggle the RSTN pin if already powered on) the TUSB211A-Q1.
3. Using SMA cables, connect the oscilloscope and the USB-IF host-side test fixture to the TUSB211A-Q1.
4. Enable the host to transmit USB TEST_PACKET.
5. Execute the oscilloscope USB compliance software.
6. Repeat the above steps to re-test TUSB211A-Q1 with a different EQ setting (must reset to change).

7.2.2.1.2 For a Device Side Application

1. Configure the TUSB211A-Q1 to the desired EQ setting.
2. Power on (or toggle the RSTN pin if already powered on) the TUSB211A-Q1.
3. Connect a USB host, the USB-IF device-side test fixture, and USB device to the TUSB211A-Q1. Ensure that the USB-IF device test fixture is configured to the 'INIT' position.
4. Allow the host to enumerate the device.
5. Enable the device to transmit USB TEST_PACKET.
6. Using SMA cables, connect the oscilloscope to the USB-IF device-side test fixture and ensure that the device-side test fixture is configured to the 'TEST' position.
7. Execute the oscilloscope USB compliance software.
8. Repeat the above steps to re-test TUSB211A-Q1 with a different EQ setting (must reset to change).

7.2.3 Application Curves

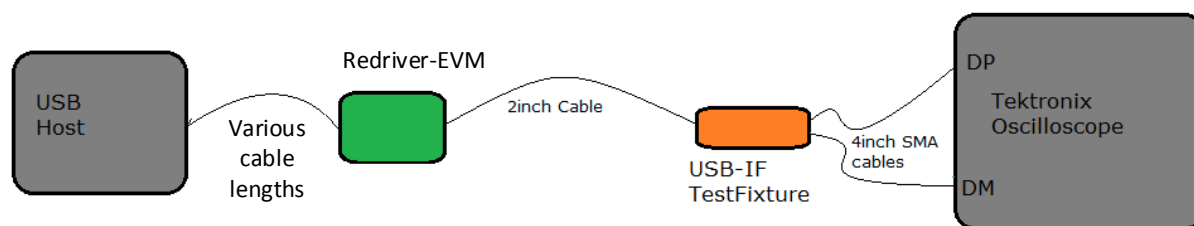


図 7-2. Near End Eye Measurement Set-Up With Pre-Channel Cable

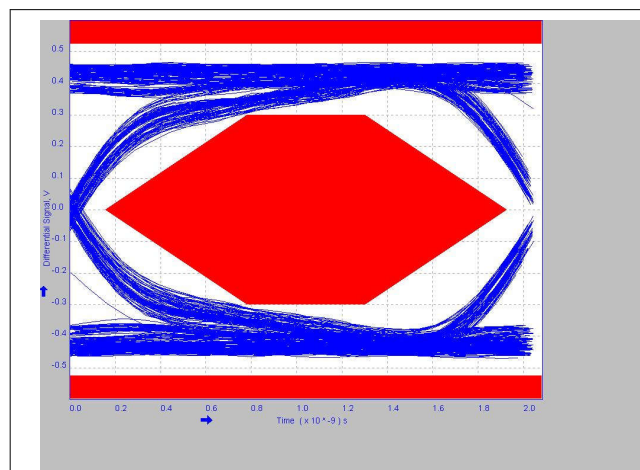


図 7-3. 2 Meter Pre-Channel Without TUSB211A-Q1

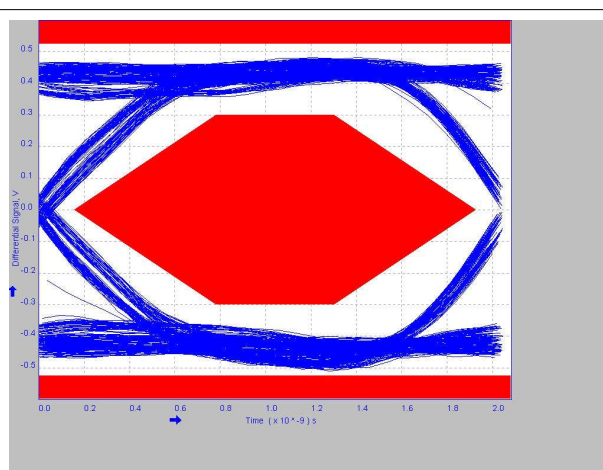


図 7-4. 2 Meter Pre-Channel With TUSB211A-Q1 EQ=1

7.2.3 Application Curves (continued)

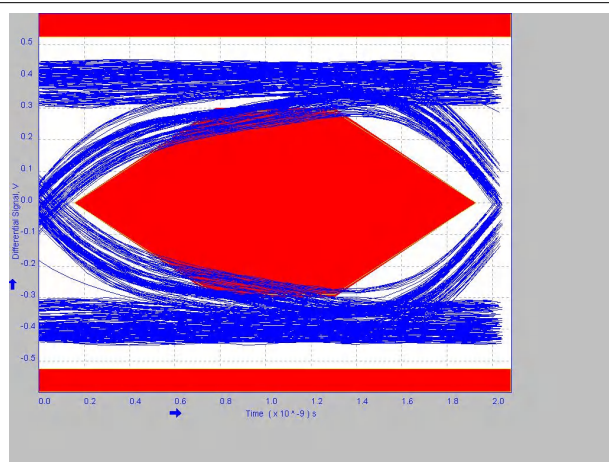


図 7-5. 5 Meter Without TUSB211A-Q1

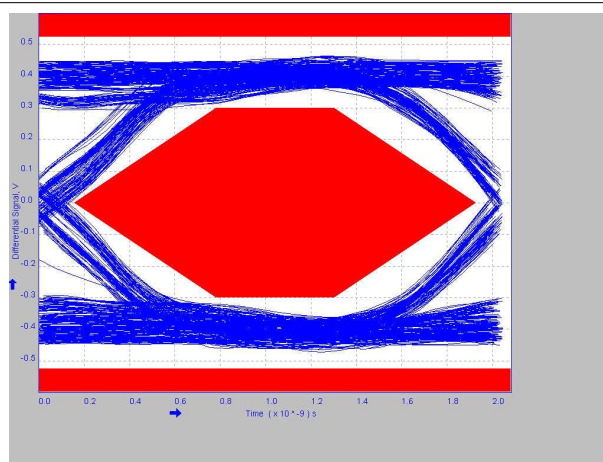


図 7-6. 5 Meter Pre-Channel With TUSB211A-Q1 EQ=1

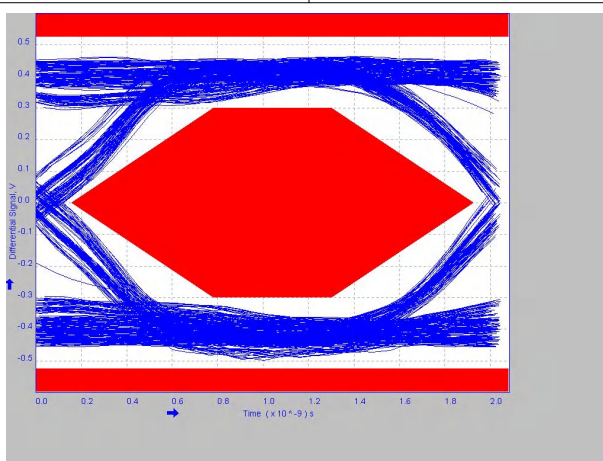


図 7-7. 5 Meter Pre-Channel With TUSB211A-Q1 EQ=2

7.2.3 Application Curves (continued)

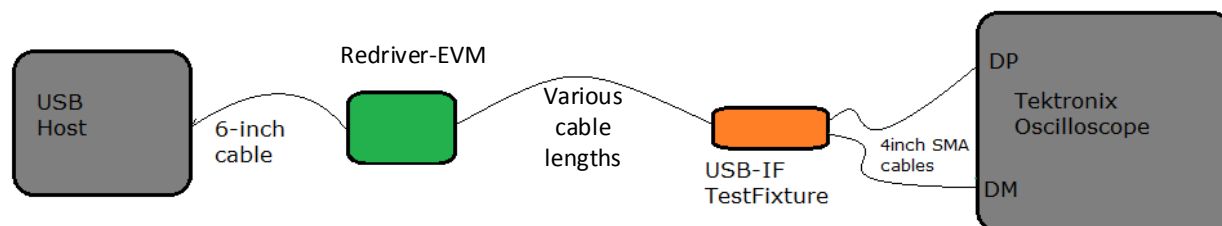


図 7-8. Near End Eye Measurement Set-Up With Post-Channel Cable

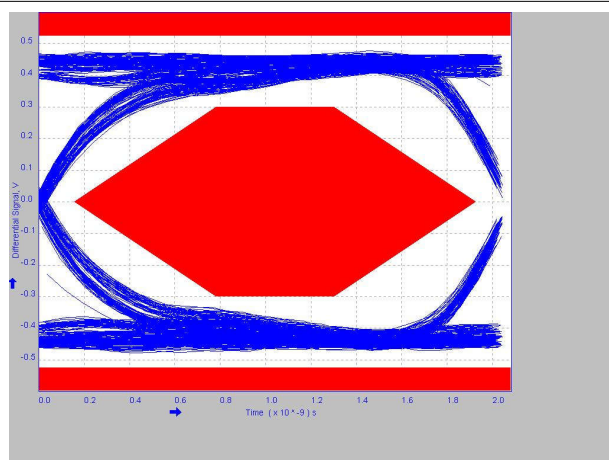


図 7-9. 1 Meter Post-Channel Without TUSB211A-Q1

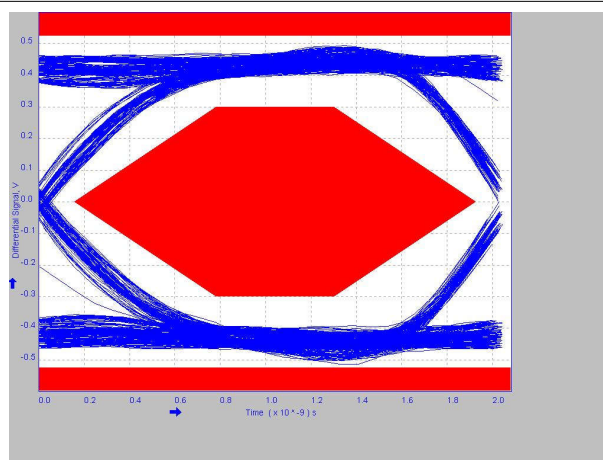


図 7-10. 1 Meter Post-Channel With TUSB211A-Q1 EQ=0

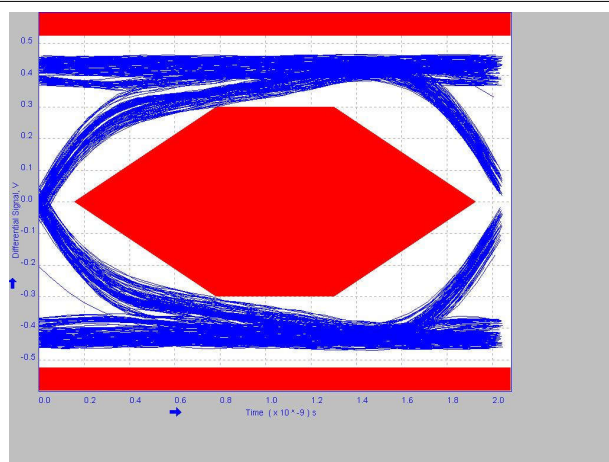


図 7-11. 2 Meter Post-Channel Without TUSB211A-Q1

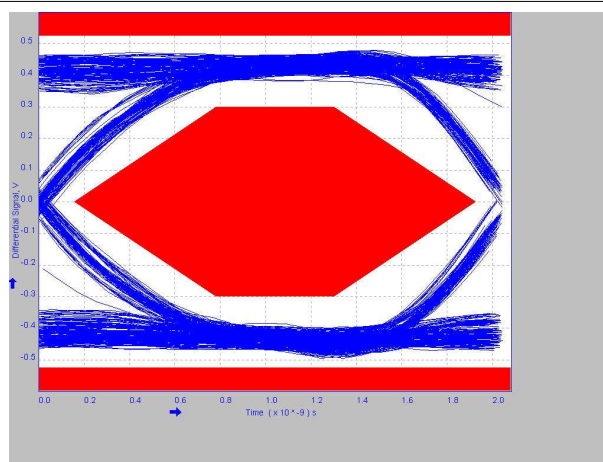


図 7-12. 2 Meter Post-Channel With TUSB211A-Q1 EQ=1

7.2.3 Application Curves (continued)

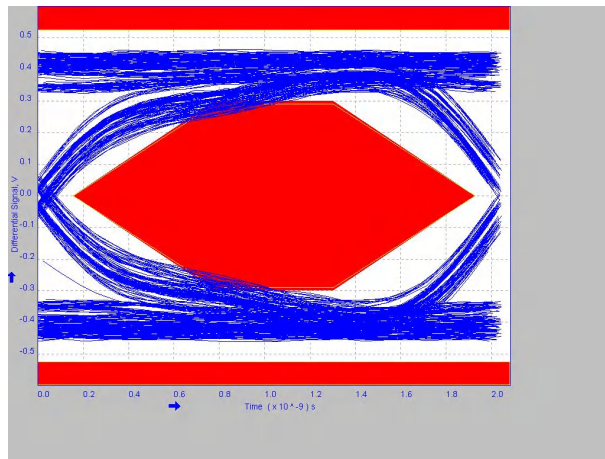


図 7-13. 4 Meter Post-Channel Without TUSB211A-Q1

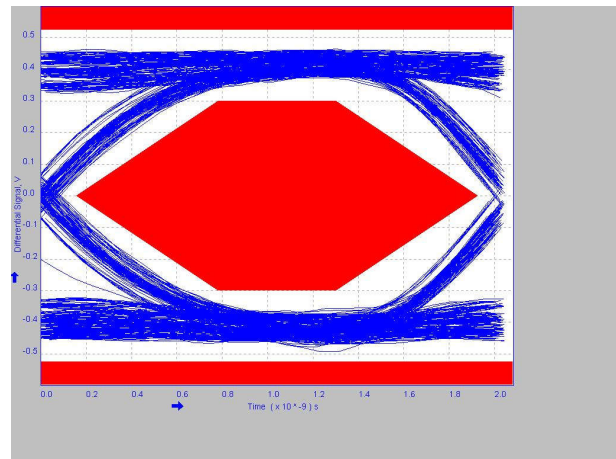


図 7-14. 4 Meter Post-Channel With TUSB211A-Q1 EQ=2

7.3 Power Supply Recommendations

On power up, the interaction of the RSTN pin and power on ramp could result in digital circuits not being set correctly. The device should not be enabled until the power on ramp has settled to the minimum recommended supply voltage or higher for a correct power on reset of the digital circuitry. If RSTN cannot be held low by the microcontroller or other circuitry until the power on ramp has settled, then an external capacitor from the RSTN pin to GND is required to hold the device in the low power reset state.

The RC time constant should be larger than five times of the power on ramp time (0 to V_{CC}). With a typical internal pullup resistance of 500k Ω , the recommended minimum external capacitance is calculated as:

$$[Ramp\ Time \times 5] \div [500\ k\Omega] \quad (1)$$

7.4 Layout

7.4.1 Layout Guidelines

Although the land pattern has matched trace width to pad width, optimal impedance control is based on the user's own PCB stack-up. The recommendation is to maintain 90 Ω differential routing underneath the device.

7.4.2 Layout Example

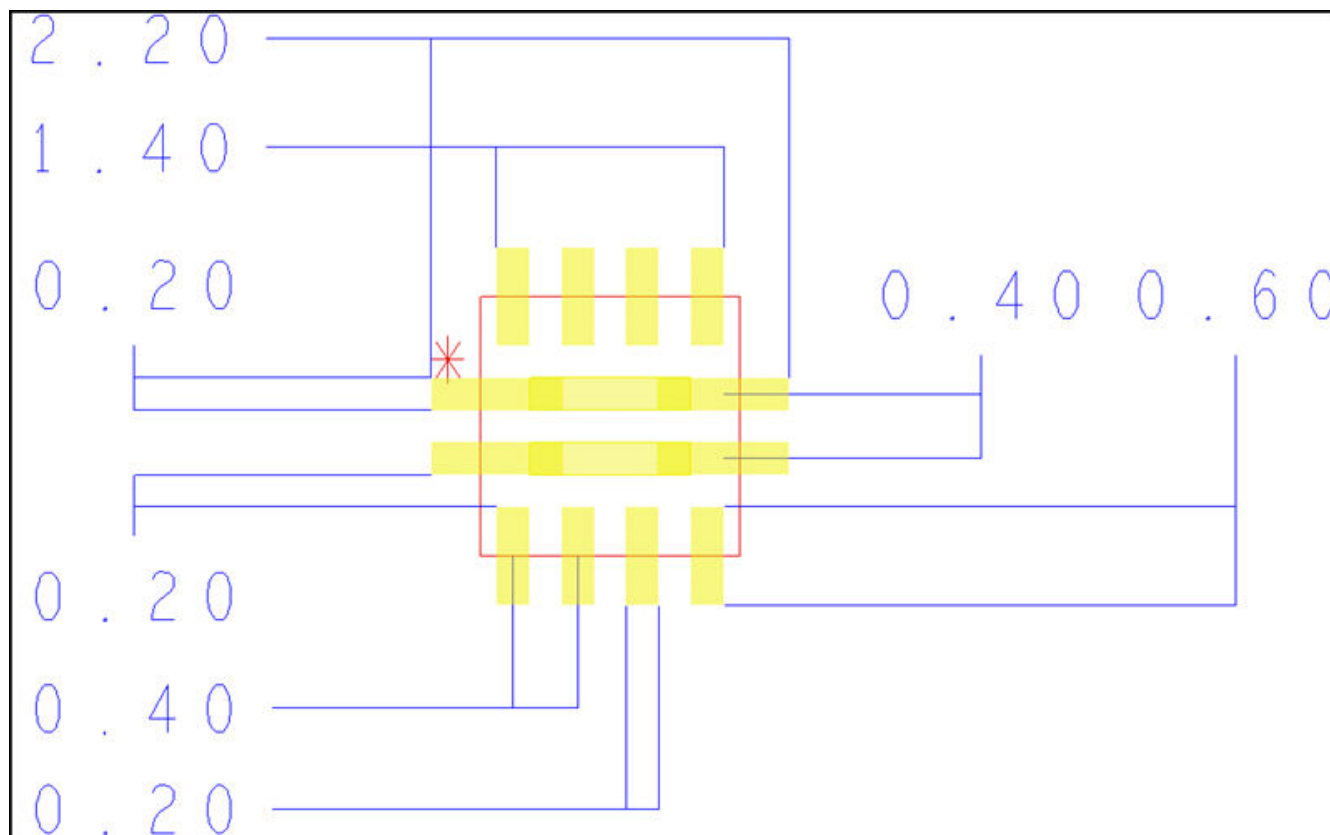


図 7-15. DP and DM Routing Underneath Device Package

8 Device and Documentation Support

8.1 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。
[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

8.2 サポート・リソース

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テキサス・インスツルメンツ E2E™ is a trademark of Texas Instruments.

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ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

8.5 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

9 Revision History

DATE	REVISION	NOTES
February 2024	*	Initial Release

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TUSB211ARWBRQ1	Active	Production	X2QFN (RWB) 12	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	1Q
TUSB211ARWBRQ1.A	Active	Production	X2QFN (RWB) 12	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	1Q
TUSB211ARWBTQ1	Active	Production	X2QFN (RWB) 12	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	1Q
TUSB211ARWBTQ1.A	Active	Production	X2QFN (RWB) 12	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	1Q

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

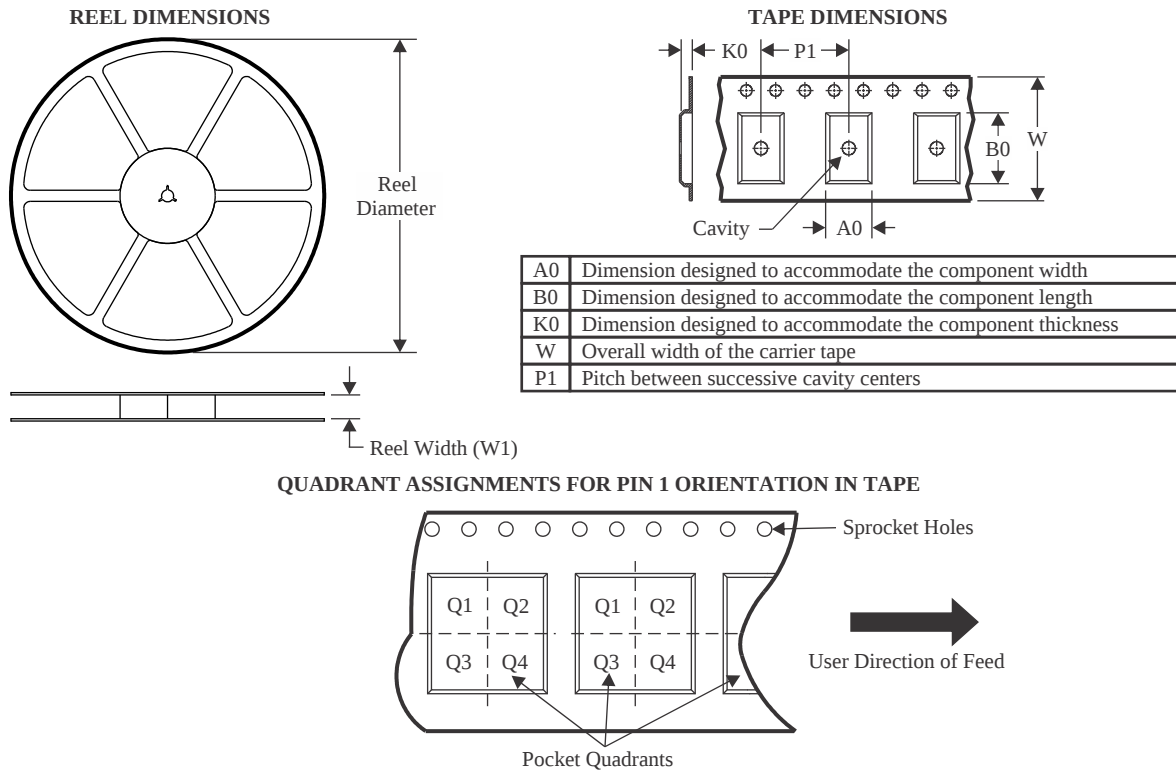
OTHER QUALIFIED VERSIONS OF TUSB211A-Q1 :

- Catalog : [TUSB211A](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION



*All dimensions are nominal

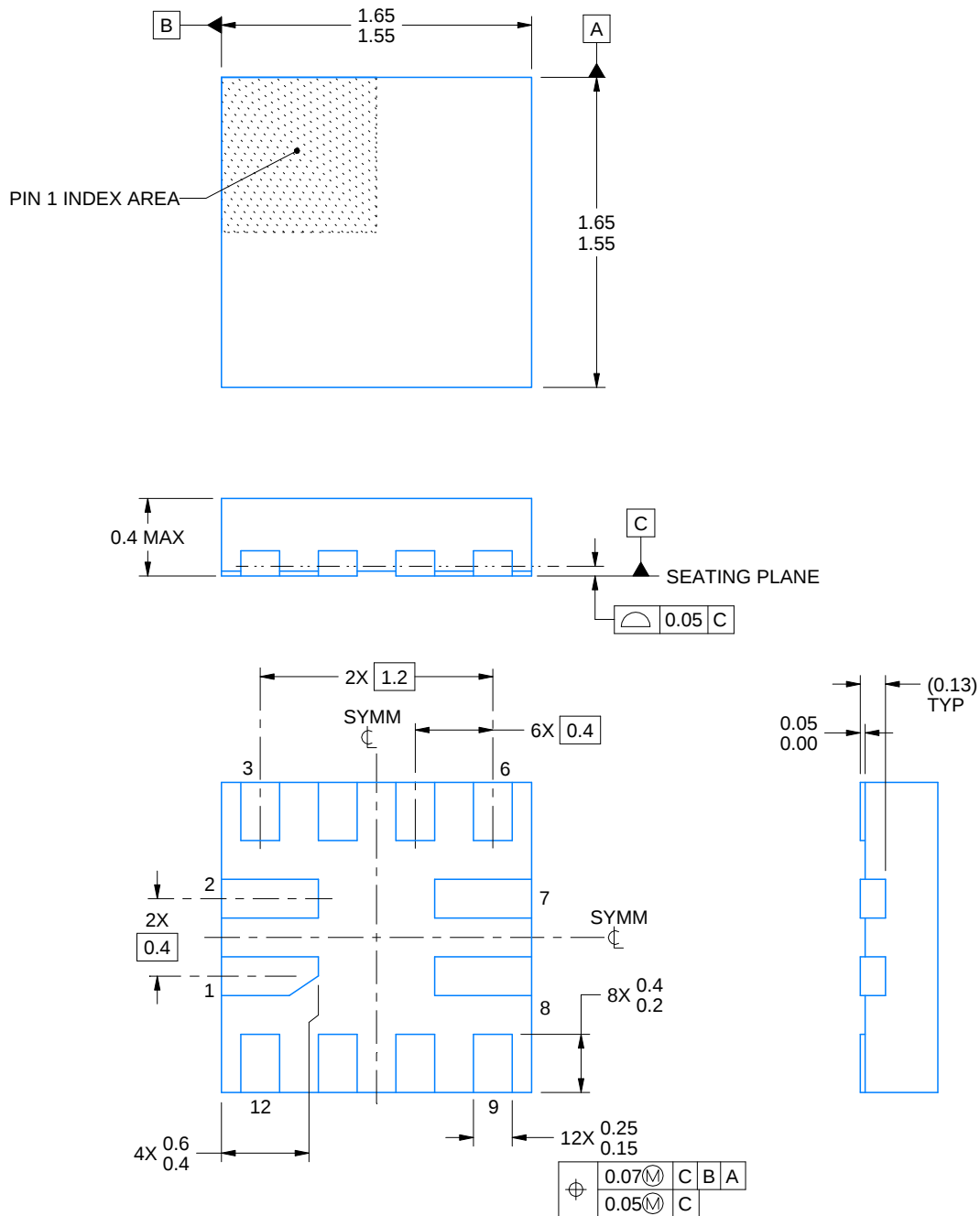
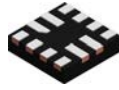
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TUSB211ARWBRQ1	X2QFN	RWB	12	3000	180.0	9.5	1.8	1.8	0.45	4.0	8.0	Q1
TUSB211ARWBTQ1	X2QFN	RWB	12	250	180.0	9.5	1.8	1.8	0.45	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TUSB211ARWBRQ1	X2QFN	RWB	12	3000	189.0	185.0	36.0
TUSB211ARWBTQ1	X2QFN	RWB	12	250	189.0	185.0	36.0



4221631/B 07/2017

NOTES:

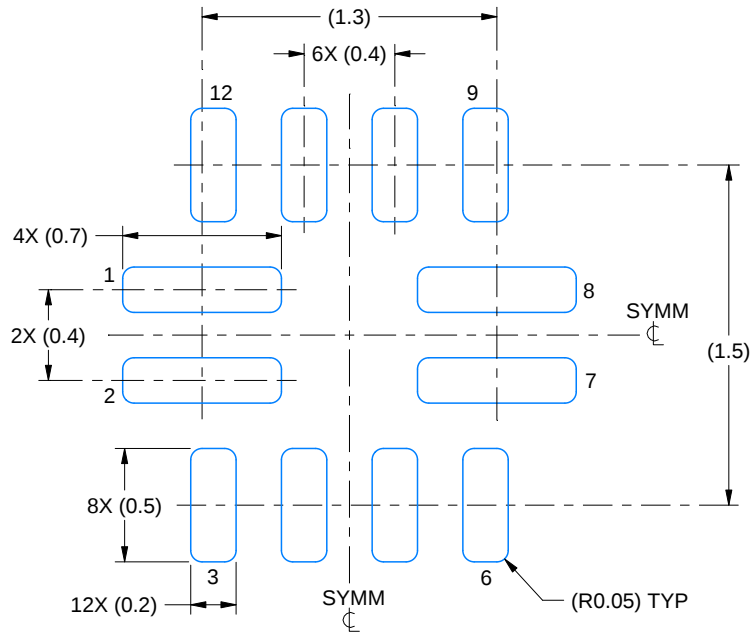
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

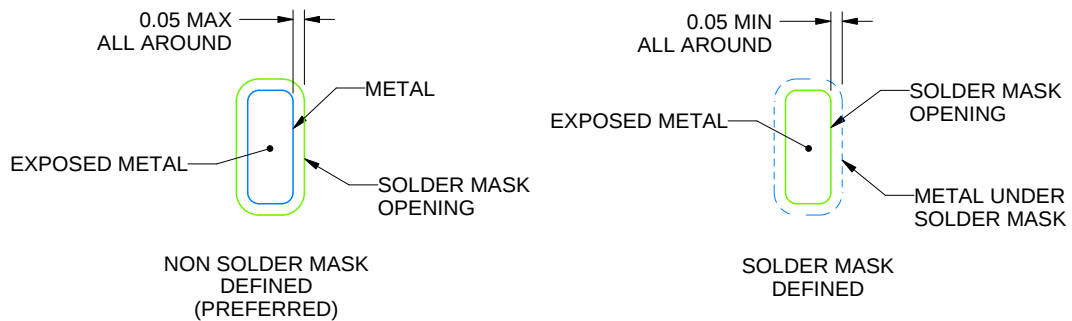
RWB0012A

X2QFN - 0.4 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:30X



SOLDER MASK DETAILS

4221631/B 07/2017

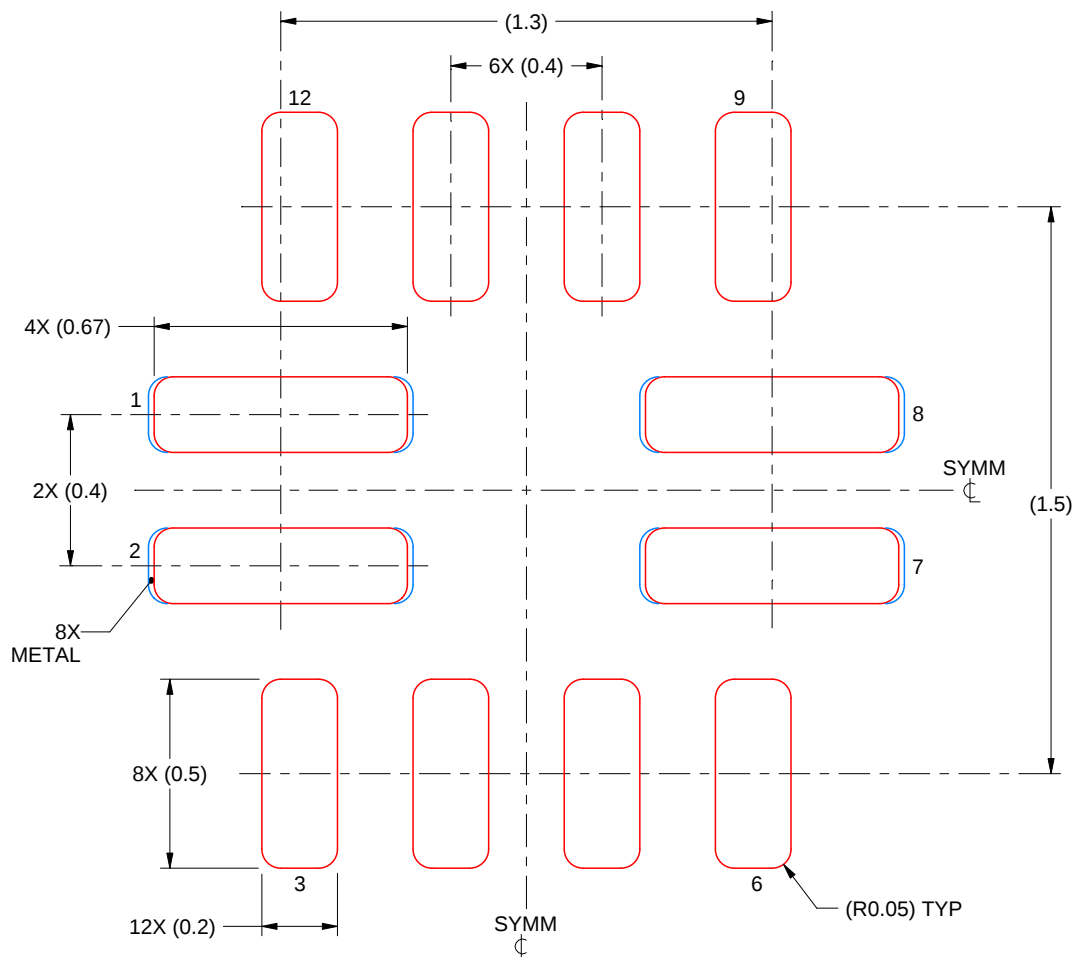
NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slue271).

RWB0012A

X2QFN - 0.4 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE BASED ON 0.1 mm THICK STENCIL

PADS 1,2,7 & 8
96% PRINTED SOLDER COVERAGE BY AREA
SCALE:50X

4221631/B 07/2017

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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